

IXFH14N80P

IXFH14N80P Information

www.helsonec.com	Part Number Manufacturer Category Description Package		
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXFH14N80P Specifications

Manufacturer Part Number	IXFH14N80P	
Manufacturer	IXYS	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Single	
Package	TO-247-3	
Series	HiPerFET?, PolarHT?	
FET Type	N-Channel	
Technology	MOSFET (Metal Oxide)	
Drain to Source Voltage (Vdss)	800V	
Current - Continuous Drain (Id) @ 25°C	14A (Tc)	
Drive Voltage (Max Rds On, Min Rds On)	10V	
Vgs(th) (Max) @ Id	5.5V @ 4mA	
Gate Charge (Qg) (Max) @ Vgs	61nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds	3900pF @ 25V	
Vgs (Max)	±30V	
FET Feature	-	
Power Dissipation (Max)	400W (Tc)	
Rds On (Max) @ Id, Vgs	720 mOhm @ 500mA, 10V	
Operating Temperature	-55°C ~ 150°C (TJ)	
Mounting Type	Through Hole	
Supplier Device Package	TO-247AD (IXFH)	
Package / Case	TO-247-3	
	Report errors?	

IXFH14N80P Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH14N80P Payment Methods



IXFH14N80P Shipping Methods



If you have any question about IXFH14N80P, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com